

SOT-23 Plastic-Encapsulate Transistors

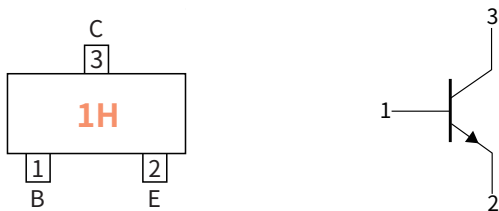
Features

- Power dissipation of 300mW
- High stability and high reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

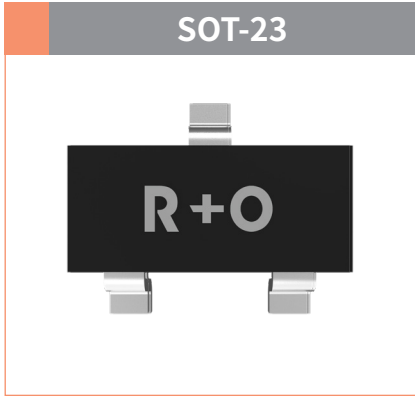
Mechanical Data

- Case: SOT-23
Molding compound meets UL 94V-0 flammability rating, RoHS-compliant,halogen-free
- Terminals: Solder plated, solderable per MIL-STD-750,Method 2026

Function Diagram



Collector-Base Voltage
VCBO 60V
Collector Current
0.5 Ampere



Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Collector-Base Voltage	V_{CBO}	V	60
Collector-Emitter Voltage	V_{CEO}		60
Emitter-Base Voltage	V_{EBO}		4.0
Collector Current	I_C	A	0.5
Collector Power Dissipation	P_C	mW	300
Storage temperature	T_{stg}	°C	-55 ~+150
Junction temperature	T_j	°C	150
Typical Thermal Resistance	$R_{\theta J-A}$	°C /W	625

Electrical Characteristics (Ta=25°C Unless otherwise noted)

PARAMETER	SYMBOL	UNIT	Condition	Min	Typ	Max
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	V	$I_C=100\mu A, I_E=0$	60	—	—
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$		$I_C=1.0mA, I_B=0$	60	—	—
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$		$I_E=100\mu A, I_C=0$	4.0	—	—
Collector-Base cut-off current	I_{CBO}	μA	$V_{CB}=60V, I_E=0$	—	—	0.1
Collector- emitter cut-off current	I_{CEO}		$V_{CE}= 60V, I_E=0$	—	—	1.0
Emitter-Base cut-off current	I_{EBO}		$V_{EB}= 4.0V, I_C=0$	—	—	0.1
DC Current Gain	$h_{FE (1)}$	—	$I_C=10mA \ V_{CE}= 1.0V$	100	—	400
	$h_{FE (2)}$	—	$I_C=100mA \ V_{CE}= 1.0V$	100	—	—
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V	$I_C= 100mA \ I_B= 10mA$	—	—	0.25
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	V	$I_C= 100mA \ I_B= 10mA$	—	—	1.2

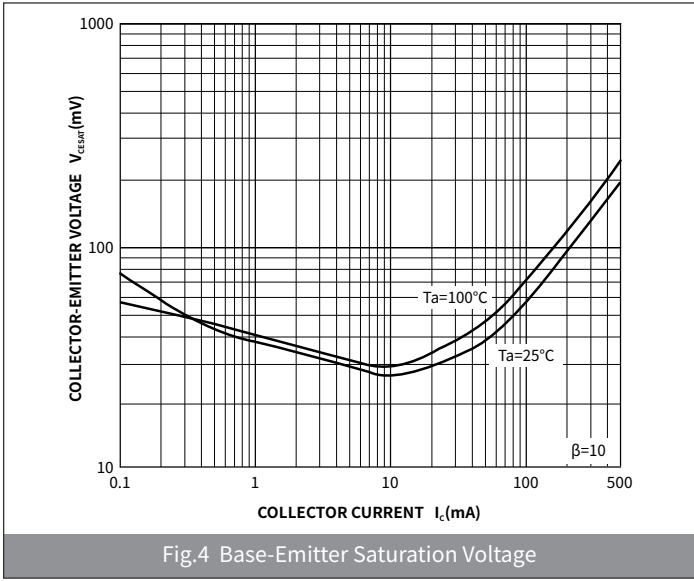
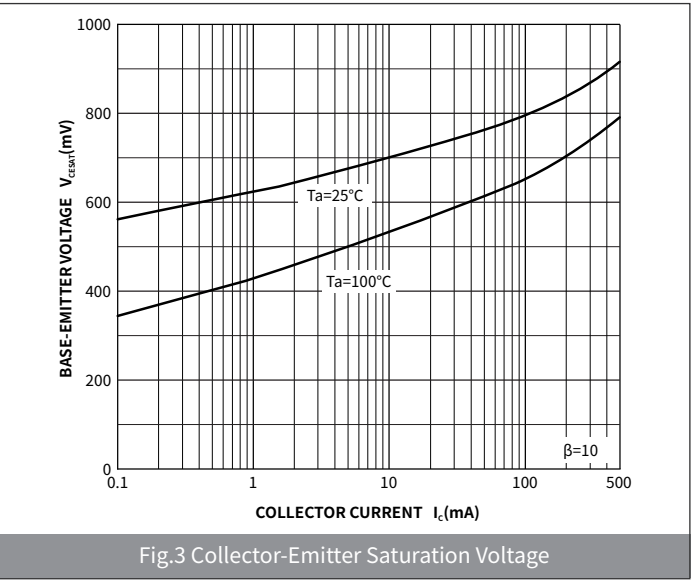
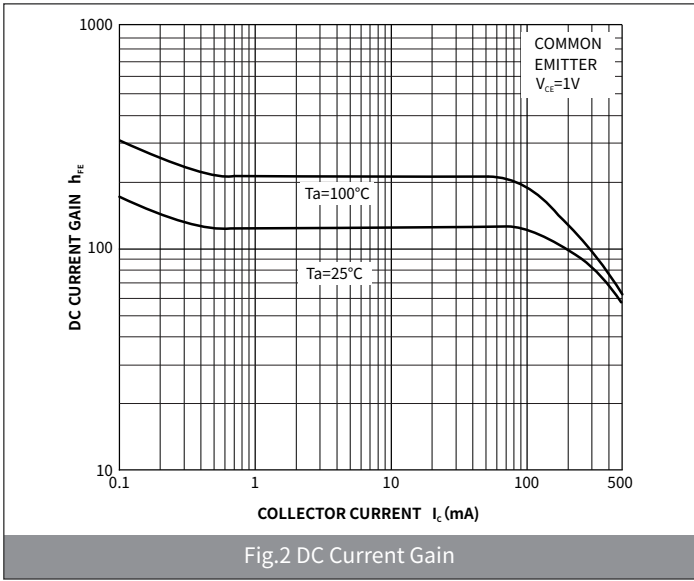
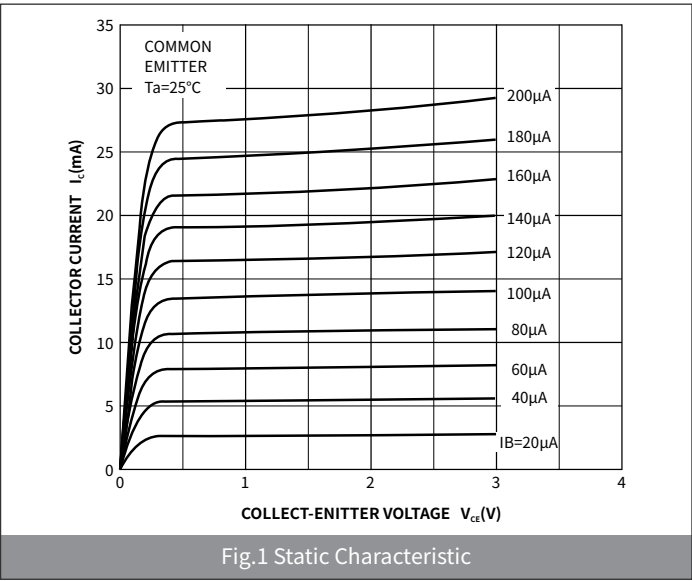
● Small-signal Characteristics

ITEM	SYMBOL	Condition	UNIT	Min	Typ	Max
Transition frequency	f_T	$I_C = 10\text{mA}$, $V_{CE} = 2.0\text{V}$	MHz	—	100	—

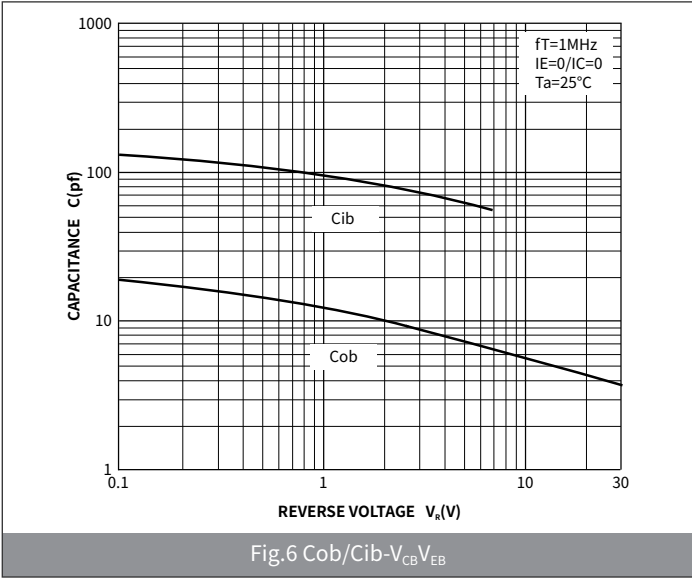
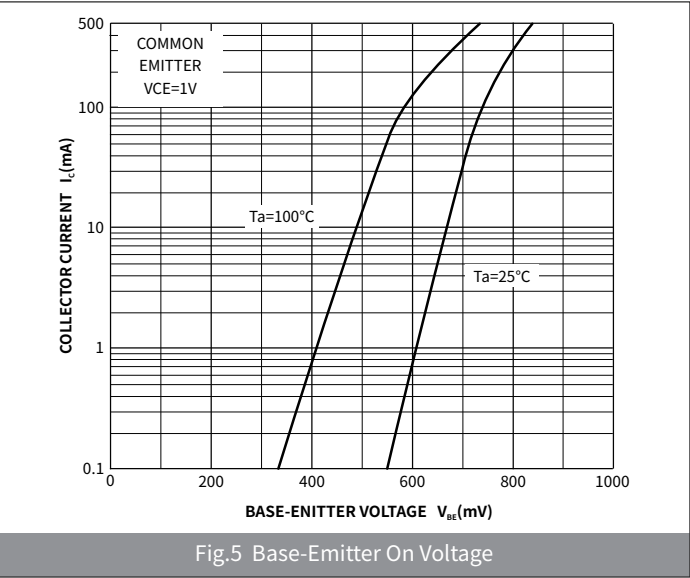
● Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-23	R1	0.008	3000	45000	180000	7"

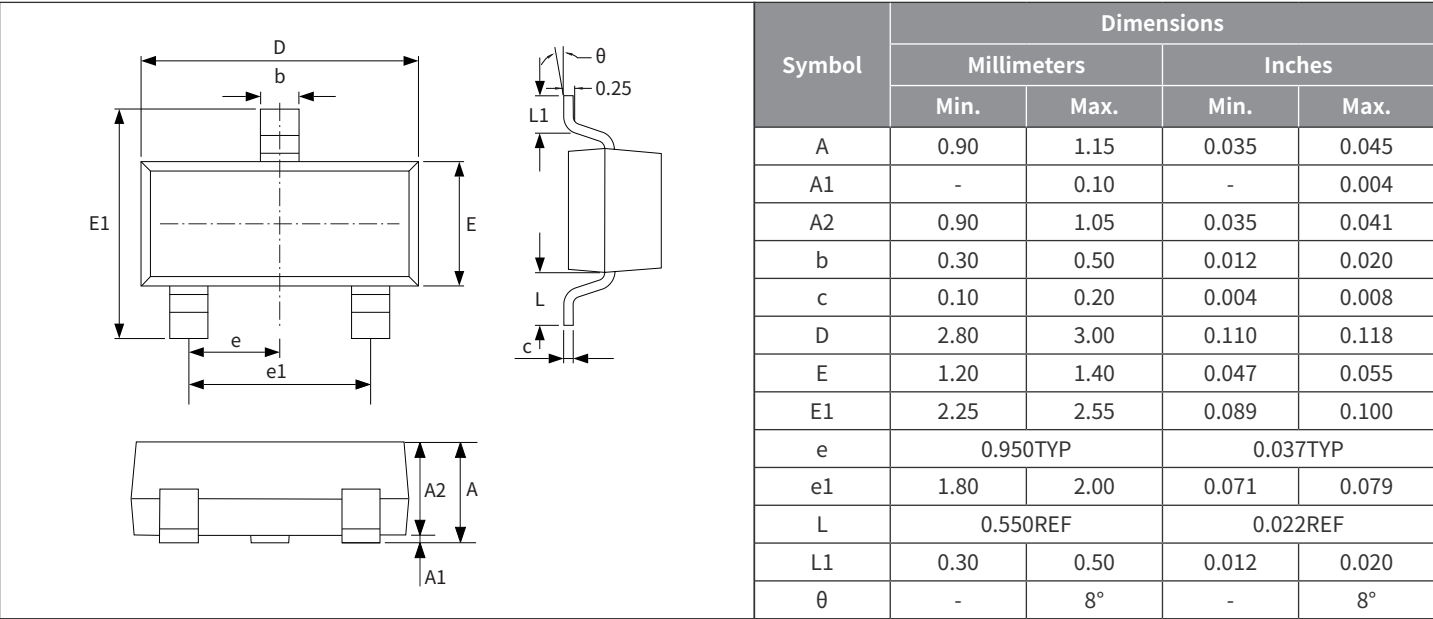
● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



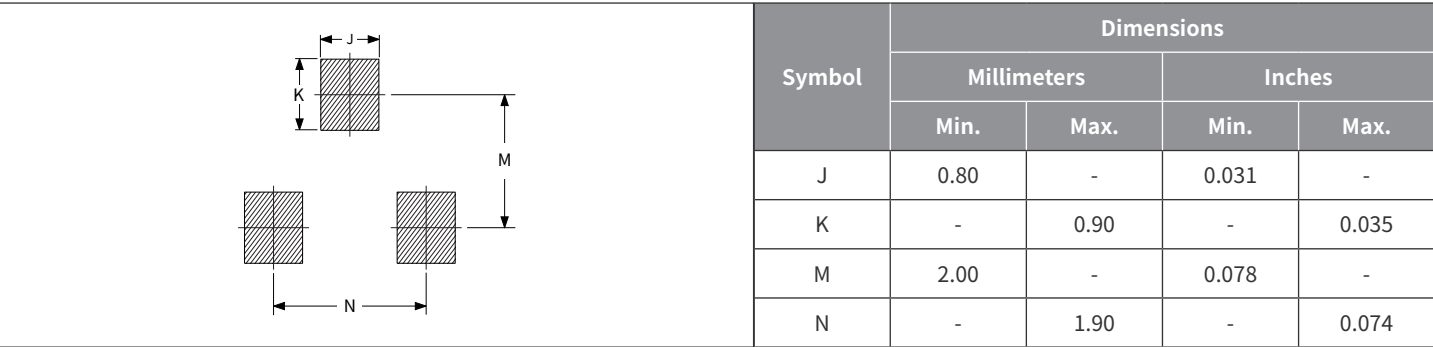
● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



● Package Outline Dimensions (SOT-23)



● Suggested Pad Layout



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